## <u>SENSITRON</u> SEMICONDUCTOR

SHDC625052 SHDC625052P SHDC625052N SHDC625052D

TECHNICAL DATA DATA SHEET 5191, Rev. -

# HERMETIC SILICON CARBIDE RECTIFIER

**DESCRIPTION:** A 1200-VOLT, 10 AMP POWER SILICON CARBIDE RECTIFIER IN A CERAMIC HERMETIC TO-254 PACKAGE (GLASS SEALS NOT AVAILABLE FOR THIS VOLTAGE)

### FEATURES:

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR
- **High Frequency Option** Non-magnetic Glidcop leads are available for improved performance at high frequency; use part number prefix SHDG

SYMBOL   PIV   Io	MAX. 1200 10	UNITS Volts Amps
lo	10	Amps
Ι <sub>Ο</sub>	5	Amps
I <sub>FRM</sub>	30	Amps
I <sub>FSM</sub>	100	Amps
P <sub>d</sub>	30	W
R <sub>θJC</sub>	1.50	°C/W
Top, Tstg	-55 to +200	°C
_	I <sub>FSM</sub> P <sub>d</sub> R <sub>θJC</sub> Top, Tstg	I <sub>FSM</sub> 100         P <sub>d</sub> 30         R <sub>θJC</sub> 1.50         Top, Tstg       -55 to

\* Note: SiC semiconductors will handle at or above this operating and storage temperature. However, extended operational use of the packaged device above 175C may reduce its future performance. All qualification testing and screening per MIL-PRF-19500 will only be performed to 175C.

### ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TYP	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP ( $I_f = 5 \text{ A PER LEG}$ ) $V_f T_j=25 \text{ °C}$		1.80	
T <sub>J</sub> =150 °C	2.55	3.00	Volts
MAXIMUM REVERSE CURRENT (1200V PIV PER LEG) $I_r$ $T_J = 25 °C$	0.05	0.20	
T <sub>J</sub> = 150 °C	0.10	1.00	mA
TOTAL CAPACITIVE CHARGE ( $V_R$ = 1200V, $I_F$ = 5A, di/dt = 500A/µs) $Q_C$	28	N/A	nC
JUNCTION CAPACITANCE ( $V_r = 5V$ ) per leg $C_T$	450		pF

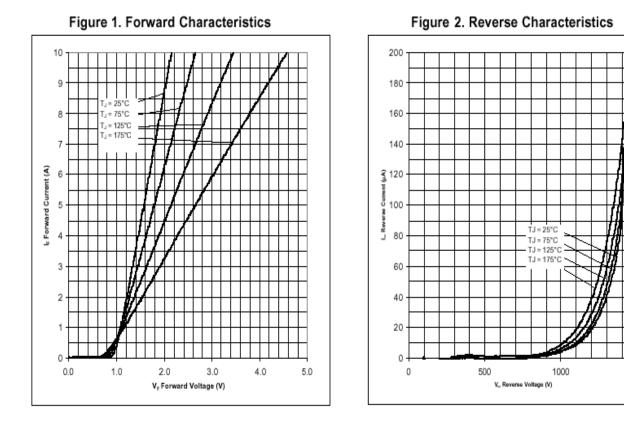
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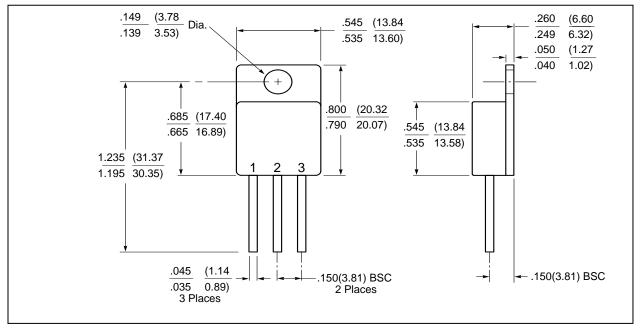
SHDC625052 SHDC625052P SHDC625052N SHDC625052D

1500

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### **MECHANICAL DIMENSIONS**



## SENSITRON SEMICONDUCTOR

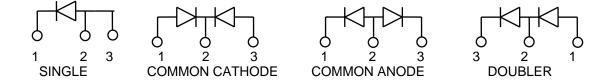
## TECHNICAL DATA

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### PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER/COMMON CATHODE (P)	ANODE 1	COMMON	ANODE 2
		CATHODE	
DUAL RECTIFIER/COMMON ANODE (N)	CATHODE 1	COMMON	CATHODE 2
		ANODE	
DUAL RECTIFIER/DOUBLER (D)	ANODE	ANODE/	CATHODE
		CATHODE	

### SCHEMATIC



Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited.

Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.

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